

MC74VHCT393A

Advance Information

Dual 4-Bit Binary Ripple Counter

The MC74VHCT393A is an advanced high speed CMOS dual 4-bit binary ripple counter fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This device consists of two independent 4-bit binary ripple counters with parallel outputs from each counter stage. A ± 256 counter can be obtained by cascading the two binary counters.

Internal flip-flops are triggered by high-to-low transitions of the clock input. Reset for the counters is asynchronous and active-high. State changes of the Q outputs do not occur simultaneously because of internal ripple delays. Therefore, decoded output signals are subject to decoding spikes and should not be used as clocks or as strobes except when gated with the Clock of the VHC393.

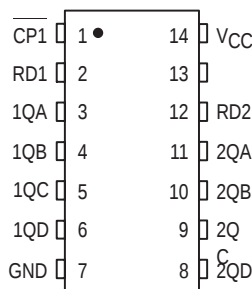
The VHCT inputs are compatible with TTL levels. This device can be used as a level converter for interfacing 3.3 V to 5.0 V because it has full 5 V CMOS level output swings.

The VHCT393A input structures provide protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. The output structures also provide protection when $V_{CC} = 0$ V. These input and output structures help prevent device destruction caused by supply voltage—input/output voltage mismatch, battery backup, hot insertion, etc.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7 V, allowing the interface of 5 V systems to 3 V systems.

- High Speed: $f_{max} = 170\text{MHz}$ (Typ) at $V_{CC} = 5\text{V}$
- Low Power Dissipation: $I_{CC} = 4\mu\text{A}$ (Max) at $T_A = 25^\circ\text{C}$
- TTL-Compatible Inputs: $V_{IL} = 0.8\text{V}$; $V_{IH} = 2.0\text{V}$
- Power Down Protection Provided on Inputs and Outputs
- Balanced Propagation Delays
- Designed for 2V to 5.5V Operating Range
- Low Noise: $V_{OLP} = 0.8\text{V}$ (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA
- ESD Performance: HBM > 2000V; Machine Model > 200V

PIN ASSIGNMENT



This document contains information on a new product. Specifications and information herein are subject to change without notice.



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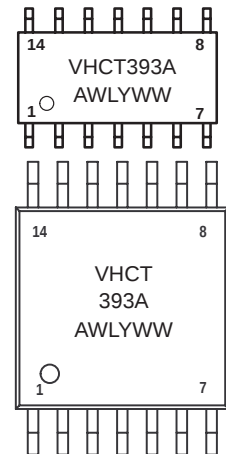
<http://onsemi.com>

MARKING DIAGRAMS

SOIC-14
D SUFFIX
CASE 751A

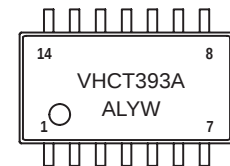


TSSOP-14
DT SUFFIX
CASE 948G



A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week

SOIC EIAJ-14
M SUFFIX
CASE 965



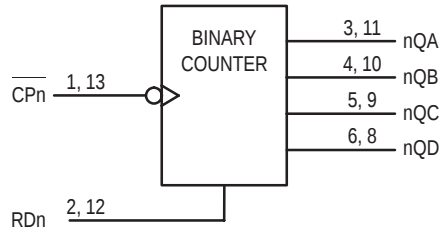
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC74VHCT393AD	SOIC-16	55 Units/Rail
MC74VHCT393ADR2	SOIC-16	1000 Units/Reel
MC74VHCT393ADT	TSSOP-16	96 Units/Rail
MC74VHCT393ADTR2	TSSOP-16	2500 Units/Reel
MC74VHCT393AM	SOIC EIAJ-16	50 Units/Rail
MC74VHCT393AMEL	SOIC EIAJ-16	2000 Units/Reel

MC74VHCT393A

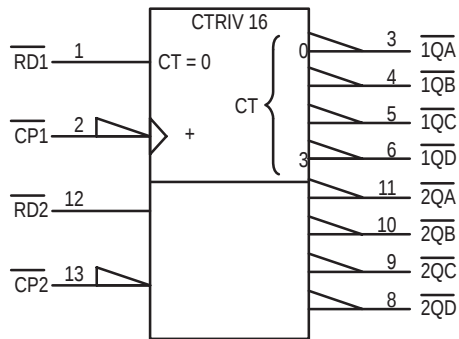
LOGIC DIAGRAM



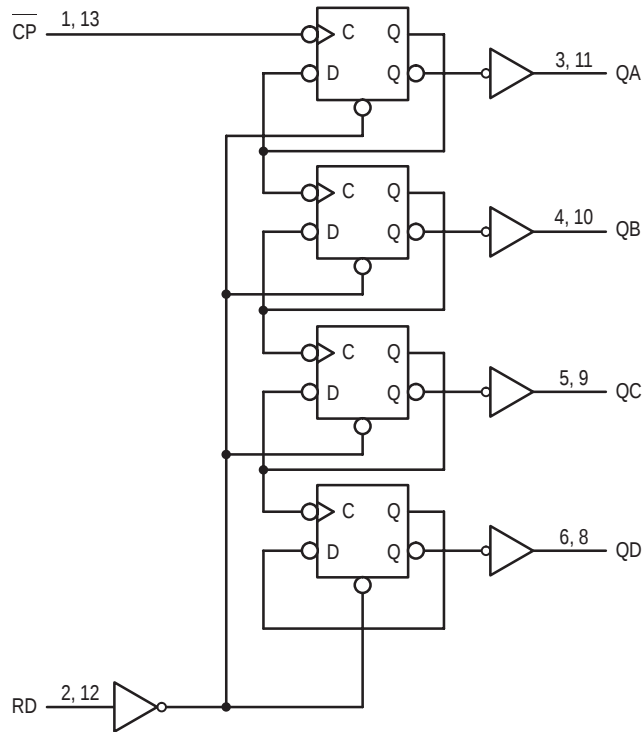
FUNCTION TABLE

Inputs		Outputs
Clock	Reset	
X	H	L
H	L	No Change
L	L	No Change
↑	L	No Change
↓	L	Next State

IEC LOGIC SYMBOL



EXPANDED LOGIC DIAGRAM



MC74VHCT393A

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	– 0.5 to + 7.0	V
V _{IN}	DC Input Voltage	– 0.5 to + 7.0	V
V _{OUT}	DC Output Voltage	– 0.5 to V _{CC} + 0.5	V
I _{IK}	Input Diode Current	– 20	mA
I _{OK}	Output Diode Current	± 20	mA
I _{OUT}	DC Output Current, per Pin	± 25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins	± 75	mA
P _D	Power Dissipation in Still Air, SOIC Packages† TSSOP Package†	500 450	mW
T _{stg}	Storage Temperature	– 65 to + 150	°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

†Derating — SOIC Packages: – 7 mW/°C from 65° to 125°C
TSSOP Package: – 6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND ≤ (V_{IN} or V_{OUT}) ≤ V_{CC}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	5.5	V
V _{IN}	DC Input Voltage	0	5.5	V
V _{OUT}	DC Output Voltage	0	V _{CC}	V
T _A	Operating Temperature	– 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time V _{CC} = 5.0 V ± 0.5 V	0	20	ns/V

The θ_{JA} of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

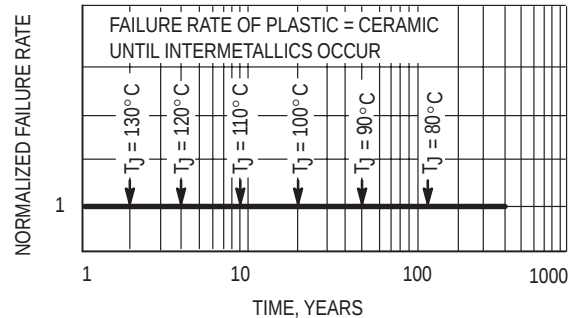


Figure 1. Failure Rate vs. Time Junction Temperature

MC74VHCT393A

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V _{CC} (V)	T _A = 25°C			T _A = ≤ 85°C		T _A = ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V _{IH}	Minimum High-Level Input Voltage		3.0 4.5 5.5	1.2 2.0 2.0			1.2 2.0 2.0		1.2 2.0 2.0		V
V _{IL}	Maximum Low-Level Input Voltage		3.0 4.5 5.5			0.53 0.8 0.8		0.53 0.8 0.8		0.53 0.8 0.8	V
V _{OH}	Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	V _{IN} = V _{IH} or V _{IL} I _{OH} = − 50 μA	3.0 4.5	2.9 4.4	3.0 4.5		2.9 4.4		2.9 4.4		V
		V _{IN} = V _{IH} or V _{IL} I _{OH} = − 4 mA	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		
		I _{OH} = − 8 mA									
V _{OL}	Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 μA	3.0 4.5		0.0 0.0	0.1 0.1		0.1 0.1		0.1 0.1	V
		V _{IN} = V _{IH} or V _{IL} I _{OL} = 4 mA	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	
		I _{OL} = 8 mA									
I _{IN}	Maximum Input Leakage Current	V _{IN} = 5.5 V or GND	0 to 5.5			± 0.1		± 1.0		± 1.0	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5			2.0		40.0		40.0	μA
I _{CC} T	Quiescent Supply Current	Input: V _{IN} = 3.4 V	5.5			1.35		1.50		1.50	mA
I _{OPD}	Output Leakage Current	V _{OUT} = 5.5 V	0.0			0.5		5.0		5.0	mA

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3.0 ns)

Symbol	Parameter	Test Conditions	T _A = 25°C			T _A = ≤ 85°C		T _A = ≤ 125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency (50% Duty Cycle)	V _{CC} = 3.3 ± 0.3 V C _L = 15pF	75	120		65		65		MHz
		C _L = 50pF	45	65		35		35		
		V _{CC} = 5.0 ± 0.5 V C _L = 15pF	125	170		105		105		
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to QA	C _L = 50pF	85	115		75		75		ns
		V _{CC} = 3.3 ± 0.3 V C _L = 15pF		8.6 11.1	13.2 16.7	1.0 1.0	15.5 19.0	1.0 1.0	15.5 19.0	
		V _{CC} = 5.0 ± 0.5 V C _L = 15pF		5.8 7.3	8.5 10.5	1.0 1.0	10.0 12.0	1.0 1.0	10.0 12.0	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to QB	C _L = 50pF		10.2 12.7	15.8 19.3	1.0 1.0	18.5 22.0	1.0 1.0	18.5 22.0	ns
		V _{CC} = 3.3 ± 0.3 V C _L = 15pF		6.8 8.3	9.8 11.8	1.0 1.0	11.5 13.5	1.0 1.0	11.5 13.5	
		V _{CC} = 5.0 ± 0.5 V C _L = 15pF		7.7 9.2	11.2 13.2	1.0 1.0	13.0 15.0	1.0 1.0	13.0 15.0	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to QC	C _L = 50pF		11.7 14.2	18.0 21.5	1.0 1.0	21.0 24.5	1.0 1.0	21.0 24.5	ns
		V _{CC} = 3.3 ± 0.3 V C _L = 15pF		7.7 9.2	11.2 13.2	1.0 1.0	13.0 15.0	1.0 1.0	13.0 15.0	
		V _{CC} = 5.0 ± 0.5 V C _L = 15pF		7.7 9.2	11.2 13.2	1.0 1.0	13.0 15.0	1.0 1.0	13.0 15.0	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to QD	C _L = 50pF		13.0 15.5	19.7 23.2	1.0 1.0	23.0 26.5	1.0 1.0	23.0 26.5	ns
		V _{CC} = 3.3 ± 0.3 V C _L = 15pF		8.5 10.0	12.5 14.5	1.0 1.0	14.5 16.5	1.0 1.0	14.5 16.5	
		V _{CC} = 5.0 ± 0.5 V C _L = 50pF		8.5 10.0	12.5 14.5	1.0 1.0	14.5 16.5	1.0 1.0	14.5 16.5	

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AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$			$T_A = \leq 85^\circ\text{C}$		$T_A = \leq 125^\circ\text{C}$		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{PHL}	Maximum Propagation Delay, RD to QN	$V_{CC} = 3.3 \pm 0.3$ V $C_L = 15$ pF		7.9	12.3	1.0	14.5	1.0	14.5	ns
		$C_L = 50$ pF		10.4	15.8	1.0	18.0	1.0	18.0	
t_{OSLH} , t_{OSHL}	Output to Output Skew	$V_{CC} = 3.3 \pm 0.3$ V $C_L = 15$ pF		5.4	8.1	1.0	9.5	1.0	9.5	ns
		$C_L = 50$ pF		6.9	10.1	1.0	11.5	1.0	11.5	
t_{OSLH} , t_{OSHL}	Output to Output Skew	$V_{CC} = 3.3 \pm 0.3$ V $C_L = 50$ pF (Note 1.)			1.5		1.5		1.5	pF
		$V_{CC} = 5.0 \pm 0.5$ V $C_L = 50$ pF (Note 1.)			1.0		1.0		1.0	pF
C_{IN}	Maximum Input Capacitance			4	10		10		10	pF

C_{PD}	Power Dissipation Capacitance (Note 2.)	Typical @ 25°C , $V_{CC} = 5.0$ V	pF
		23	

- Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.
- C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$.

NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns, $C_L = 50$ pF, $V_{CC} = 5.0$ V)

Symbol	Parameter	$T_A = 25^\circ\text{C}$		Unit
		Typ	Max	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	0.5	0.8	V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	-0.5	-0.8	V
V_{IHD}	Minimum High Level Dynamic Input Voltage		2.0	V
V_{ILD}	Maximum Low Level Dynamic Input Voltage		0.8	V

TIMING REQUIREMENTS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$		$T_A = \leq 85^\circ\text{C}$	$T_A = \leq 125^\circ\text{C}$	Unit
			Typ	Limit	Limit	Limit	
t_W	Minimum Pulse Width, CP	$V_{CC} = 3.3 \pm 0.3$ V $V_{CC} = 5.0 \pm 0.5$ V		5.0 5.0	5.0 5.0	5.0 5.0	ns
t_W	Minimum Pulse Width, RD	$V_{CC} = 3.3 \pm 0.3$ V $V_{CC} = 5.0 \pm 0.5$ V		5.0 5.0	5.0 5.0	5.0 5.0	ns
t_{rec}	Minimum Recovery Time, RD to CP	$V_{CC} = 3.3 \pm 0.3$ V $V_{CC} = 5.0 \pm 0.5$ V		5.0 4.0	5.0 4.0	5.0 4.0	ns
t_r, t_f	Minimum Input Rise and Fall Times	$V_{CC} = 3.3 \pm 0.3$ V $V_{CC} = 5.0 \pm 0.5$ V		330 100	330 100	330 100	ns

MC74VHCT393A

SWITCHING WAVEFORMS

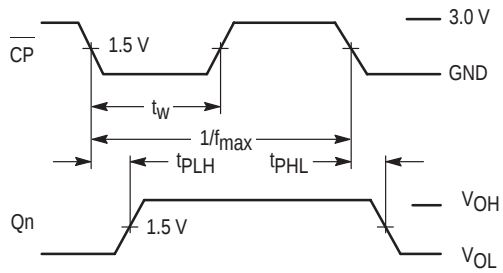


Figure 2.

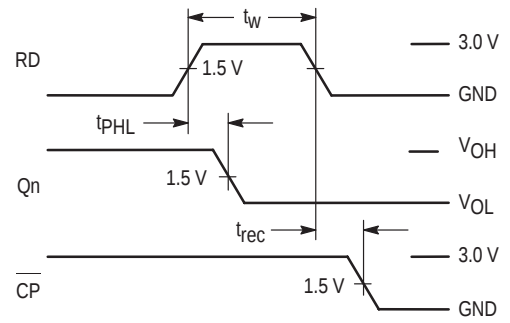
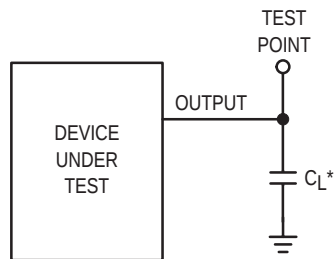


Figure 3.

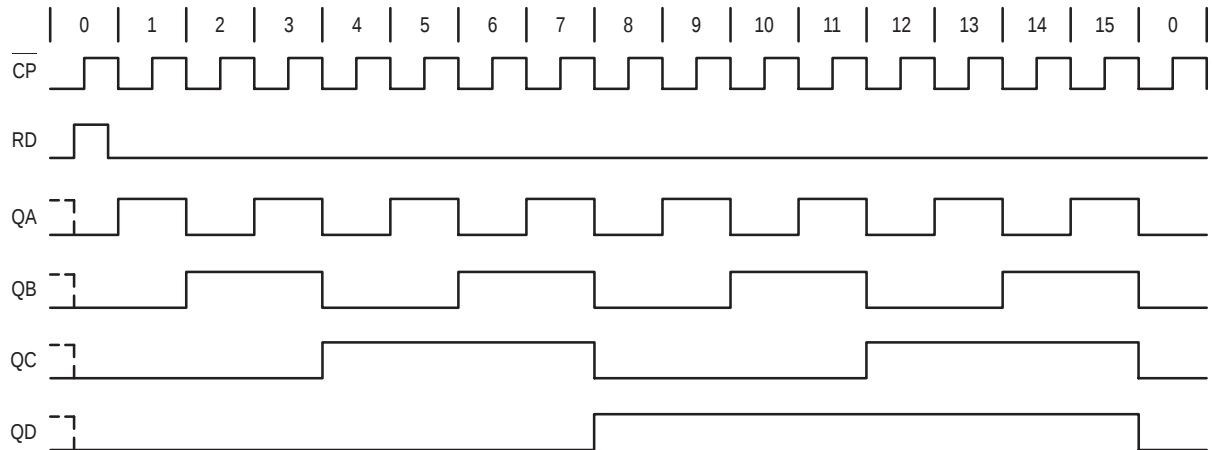


*Includes all probe and jig capacitance

Figure 4. Test Circuit

MC74VHCT393A

TIMING DIAGRAM



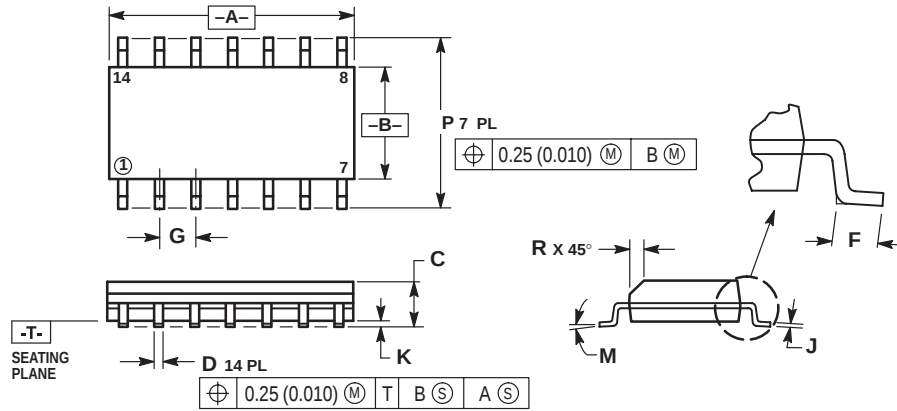
COUNT SEQUENCE

Count	Outputs			
	QD	QC	QB	QA
0	L	L	L	L
1	L	L	L	H
2	L	L	H	L
3	L	L	H	H
4	L	H	L	L
5	L	H	L	H
6	L	H	H	L
7	L	H	H	H
8	H	L	L	L
9	H	L	L	H
10	H	L	H	L
11	H	L	H	H
12	H	H	L	L
13	H	H	L	H
14	H	H	H	L
15	H	H	H	H

MC74VHCT393A

PACKAGE DIMENSIONS

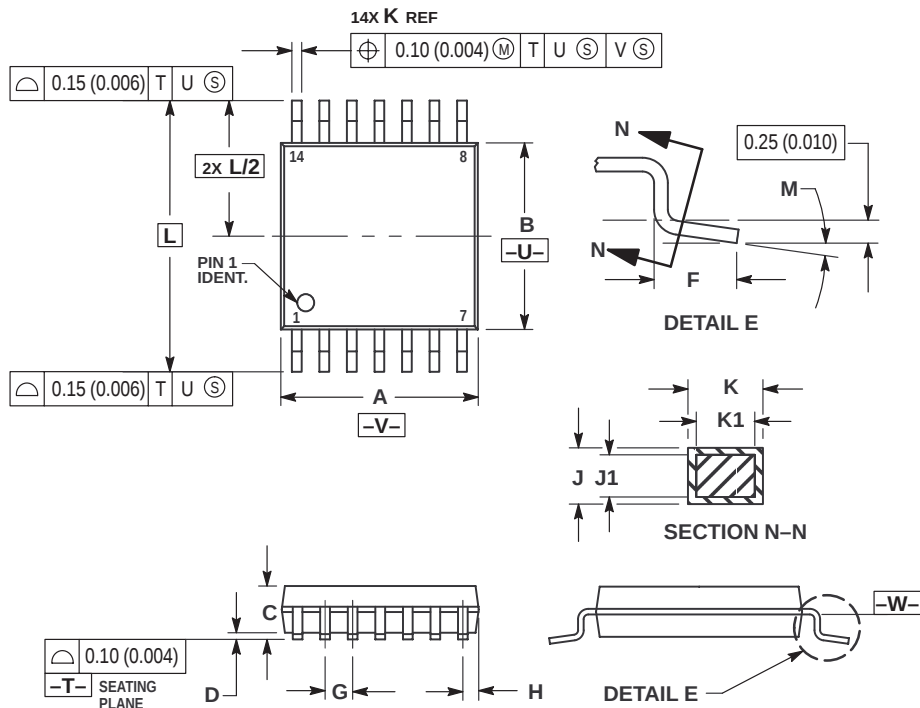
SOIC-14 D SUFFIX CASE 751A-03 ISSUE F



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

TSSOP-14 DT SUFFIX CASE 948G-01 ISSUE O



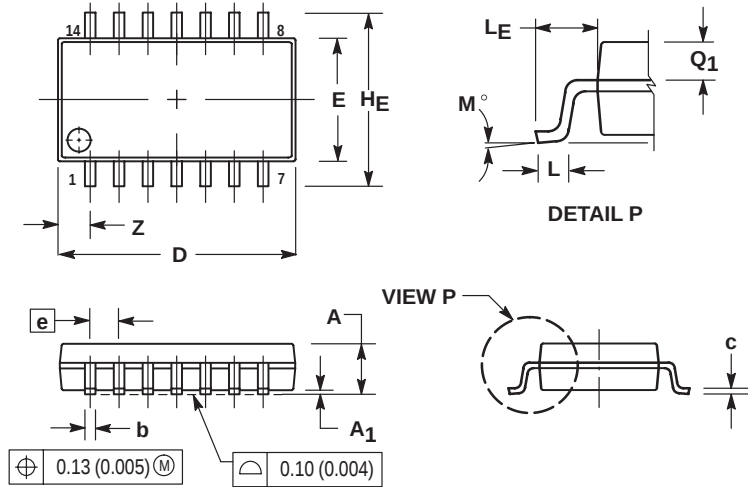
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	—	1.20	—	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

MC74VHCT393A

PACKAGE DIMENSIONS

SOIC EIAJ-14
M SUFFIX
CASE 965-01
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	—	2.05	—	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q ₁	0.70	0.90	0.028	0.035
Z	—	1.42	—	0.056

Notes

Notes

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